Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

TK2P60D

Switching Regulator Applications

• Low drain-source ON-resistance: RDS (ON) = 3.3 Ω (typ.)

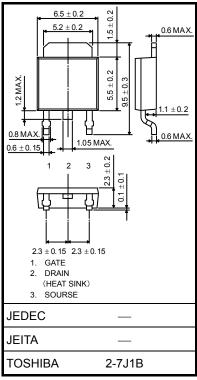
• High forward transfer admittance: $|Y_{fs}| = 1.0 \text{ S (typ.)}$

• Low leakage current: $I_{DSS} = 10 \mu A (V_{DS} = 600 V)$

• Enhancement-mode: $V_{th} = 2.4 \text{ to } 4.4 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|---------------------------|------------------------------|------------------|------------|------|
| Drain-source voltage | | V_{DSS} | 600 | V |
| Gate-source voltage | | V _{GSS} | ±30 | V |
| | DC (Note 1) | ΙD | 2 | |
| Drain current | Pulse (t = 1 ms) (Note 1) | I _{DP} | 8 | Α |
| Drain power dissipati | on (Tc = 25°C) | P _D | 60 | W |
| Single pulse avalance | ne energy (Note 2) | E _{AS} | 101 | mJ |
| Avalanche current | | I _{AR} | 2 | Α |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 6 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature range | | T _{stg} | -55 to 150 | °C |



Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

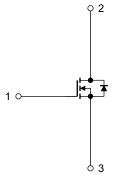
| Characteristics | Symbol | Max | Unit |
|----------------------------------------|------------------------|------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 2.08 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 125 | °C/W |

Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 44.1 mH, R_G = 25 Ω , I_{AR} = 2 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.



Start of commercial production 2009-09



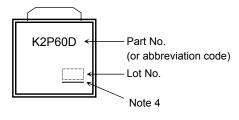
Electrical Characteristics (Ta = 25°C)

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|---------------|----------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|------|
| Gate leakage current | | I _{GSS} | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±1 | μΑ |
| Drain cut-off current | | I _{DSS} | V _{DS} = 600 V, V _{GS} = 0 V | _ | _ | 10 | μΑ |
| Drain-source break | down voltage | V (BR) DSS | $I_D = 10$ mA, $V_{GS} = 0$ V | 600 | _ | _ | V |
| Gate threshold volt | age | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.4 | _ | 4.4 | V |
| Drain-source ON-resistance | | R _{DS} (ON) | V _{GS} = 10 V, I _D = 1 A | _ | 3.3 | 4.3 | Ω |
| Forward transfer a | dmittance | Y _{fs} | V _{DS} = 10 V, I _D = 1 A | 0.3 | 1.0 | _ | S |
| Input capacitance | | C _{iss} | | - | 280 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | $V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | - | 1.5 | _ | |
| Output capacitance | | Coss | | - | 30 | _ | |
| Switching time | Rise time | t _r | V_{GS} V | | 15 | _ | |
| | Turn-on time | t _{on} | | | 35 | | ns |
| | Fall time | t _f | | | 7 | | 115 |
| | Turn-off time | t _{off} | Duty \leq 1%, $t_W = 10 \mu s^{V_{DD} \approx 200 \text{ V}}$ | | 55 | | |
| Total gate charge | | Qg | | _ | 7 | _ | nC |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 2 \text{ A}$ | _ | 4 | _ | |
| Gate-drain charge | | Q _{gd} | | _ | 3 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

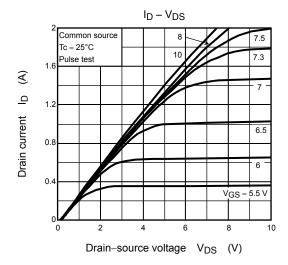
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------------------------|----------|------------------|-----------------------------------------------|-----|------|------|------|
| Continuous drain reverse current | (Note 1) | I _{DR} | _ | | _ | 2 | Α |
| Pulse drain reverse current | (Note 1) | I _{DRP} | _ | _ | _ | 8 | Α |
| Forward voltage (diode) | | V_{DSF} | I _{DR} = 2 A, V _{GS} = 0 V | | _ | -1.7 | V |
| Reverse recovery time | | t _{rr} | $I_{DR} = 2 \text{ A}, V_{GS} = 0 \text{ V},$ | | 550 | _ | ns |
| Reverse recovery charge | | Qrr | dl _{DR} /dt = 100 A/μs | | 2.2 | _ | μС |

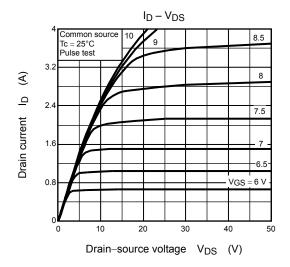
Marking

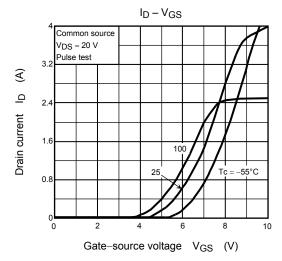


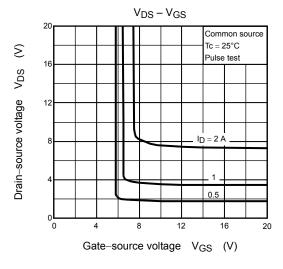
Note 4 : A line under a Lot No. identifies the indication of product Labels $\hbox{[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]}$

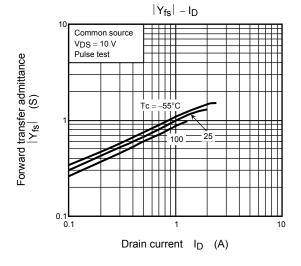
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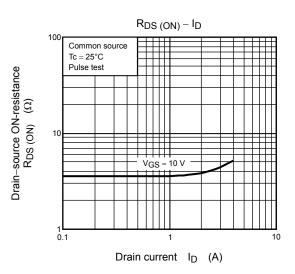


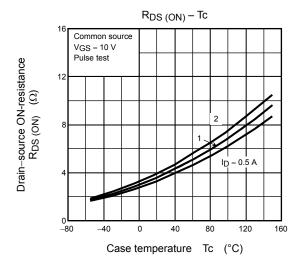


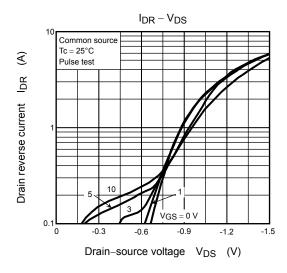


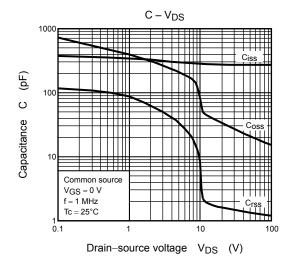


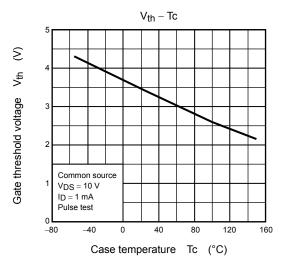


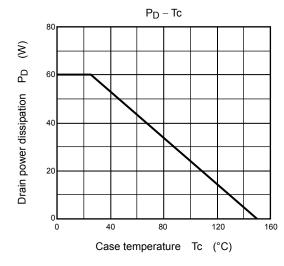


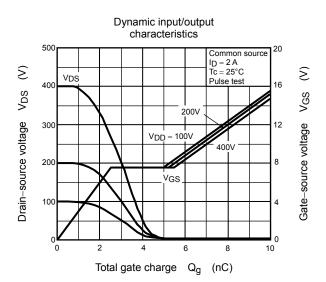


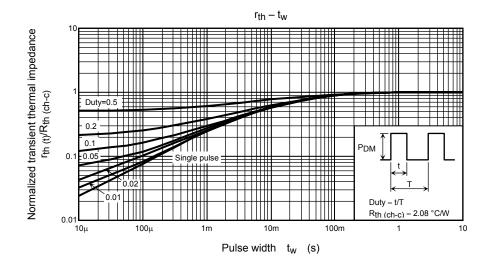


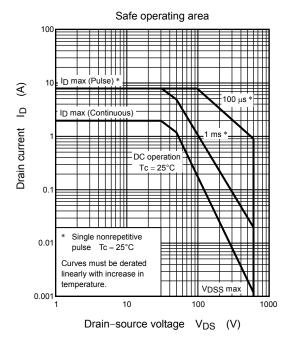


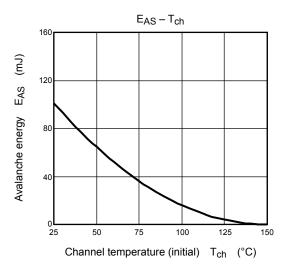


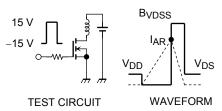












$$\begin{aligned} R_G &= 25 \ \Omega \\ V_{DD} &= 90 \ V, \ L = 44.1 \ mH \end{aligned} \qquad \text{EAS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{\text{BVDSS}}{\text{BVDSS} - \text{VDD}} \right)$$

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